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# BCR12KM-12LA

#### Triac

Medium Power Use

REJ03G0324-0100 Rev.1.00 Aug.20.2004

#### **Features**

I<sub>T (RMS)</sub>: 12 A
 V<sub>DRM</sub>: 600 V

•  $I_{FGTI}$ ,  $I_{RGTI}$ ,  $I_{RGTIII}$ : 30 mA (20 mA)<sup>Note5</sup>

• Viso: 2000 V

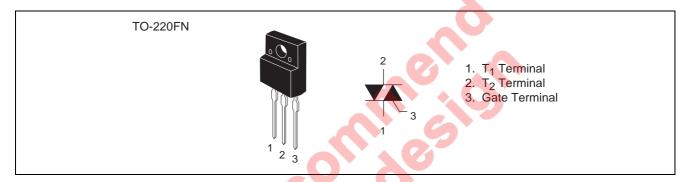
Insulated Type

• Planar Passivation Type

• UL Recognized: Yellow Card No. E223904

File No. E80271

#### **Outline**



#### **Applications**

Switching mode power supply, washing machine, copying machine, motor control, heater control, and other general purpose control applications

#### **Maximum Ratings**

| Parameter                                          | Symbol    | Voltage class | Unit  |
|----------------------------------------------------|-----------|---------------|-------|
|                                                    | Syllibol  | 12            | Offic |
| Repetitive peak off-state voltage <sup>Note1</sup> | $V_{DRM}$ | 600           | V     |
| Non-repetitive peak off-state voltage Note1        | $V_{DSM}$ | 720           | V     |

#### BCR12KM-12LA

| Parameter                      | Symbol               | Ratings      | Unit             | Conditions                                         |
|--------------------------------|----------------------|--------------|------------------|----------------------------------------------------|
| RMS on-state current           | I <sub>T (RMS)</sub> | 12           | Α                | Commercial frequency, sine full wave               |
|                                |                      |              |                  | 360° conduction, Tc = 77°C                         |
| Surge on-state current         | I <sub>TSM</sub>     | 120          | Α                | 60Hz sinewave 1 full cycle, peak value,            |
|                                |                      |              |                  | non-repetitive                                     |
| I <sup>2</sup> t for fusing    | l <sup>2</sup> t     | 60           | A <sup>2</sup> s | Value corresponding to 1 cycle of half             |
|                                |                      |              |                  | wave 60Hz, surge on-state current                  |
| Peak gate power dissipation    | $P_{GM}$             | 5            | W                |                                                    |
| Average gate power dissipation | P <sub>G (AV)</sub>  | 0.5          | W                |                                                    |
| Peak gate voltage              | $V_{GM}$             | 10           | V                |                                                    |
| Peak gate current              | I <sub>GM</sub>      | 2            | Α                |                                                    |
| Junction temperature           | Tj                   | - 40 to +125 | °C               |                                                    |
| Storage temperature            | Tstg                 | - 40 to +125 | °C               |                                                    |
| Mass                           | _                    | 2.0          | g                | Typical value                                      |
| Isolation voltage              | Viso                 | 2000         | V                | Ta = 25°C, AC 1 minute,                            |
|                                |                      |              |                  | T <sub>1</sub> ·T <sub>2</sub> ·G terminal to case |

Notes: 1. Gate open.

#### **Electrical Characteristics**

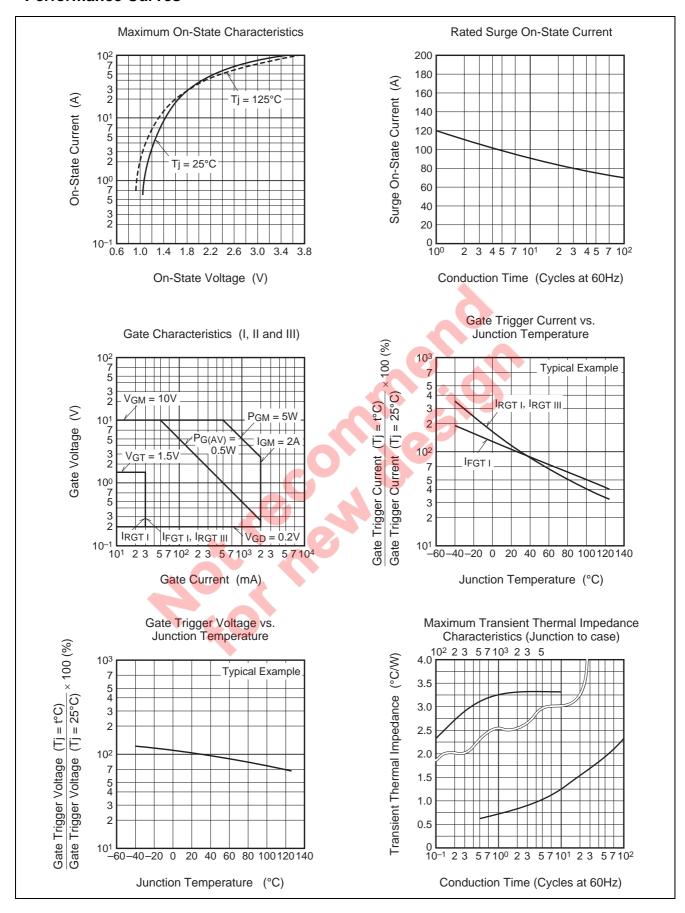
| Parameter                                                   |     | Symbol                | Min.     | Тур.                    | Max.                | Unit | Test conditions                                                 |
|-------------------------------------------------------------|-----|-----------------------|----------|-------------------------|---------------------|------|-----------------------------------------------------------------|
| Repetitive peak off-state curr                              | ent | I <sub>DRM</sub>      | _        | _                       | 2.0                 | mA   | Tj = 125°C, V <sub>DRM</sub> applied                            |
| On-state voltage                                            |     | $V_{TM}$              | _        | -                       | 1.6                 | V    | Tc = 25°C, I <sub>TM</sub> = 20 A,<br>Instantaneous measurement |
| Gate trigger voltage <sup>Note2</sup>                       | I   | $V_{FGTI}$            | _        |                         | 1.5                 | V    | $Tj = 25^{\circ}C, V_D = 6 V, R_L = 6 \Omega,$                  |
|                                                             | II  | $V_{RGTI}$            | _        | $\mathcal{A}_{\lambda}$ | 1.5                 | V    | $R_G = 330 \Omega$                                              |
|                                                             | III | $V_{RGTIII}$          | _        |                         | 1.5                 | V    |                                                                 |
| Gate trigger current <sup>Note2</sup>                       | I   | $I_{FGTI}$            |          | <b>/</b> – (            | 30 <sup>Note5</sup> | mA   | $Tj = 25^{\circ}C, V_D = 6 V, R_L = 6 \Omega,$                  |
|                                                             | II  | $I_{RGTI}$            |          | _                       | 30 <sup>Note5</sup> | mA   | $R_G = 330 \Omega$                                              |
|                                                             | III | I <sub>RGTIII</sub>   | <u> </u> | 4                       | 30 <sup>Note5</sup> | mA   |                                                                 |
| Gate non-trigger voltage                                    |     | $V_{\sf GD}$          | 0.2      | 17                      | _                   | V    | $Tj = 125^{\circ}C, V_D = 1/2 V_{DRM}$                          |
| Thermal resistance                                          |     | R <sub>th (j-c)</sub> | -0       | _                       | 3.3                 | °C/W | Junction to case <sup>Note3</sup>                               |
| Critical-rate of rise of off-stat commutating voltage Note4 | е   | (dv/dt)c              | 10       | _                       | _                   | V/µs | Tj = 125°C                                                      |

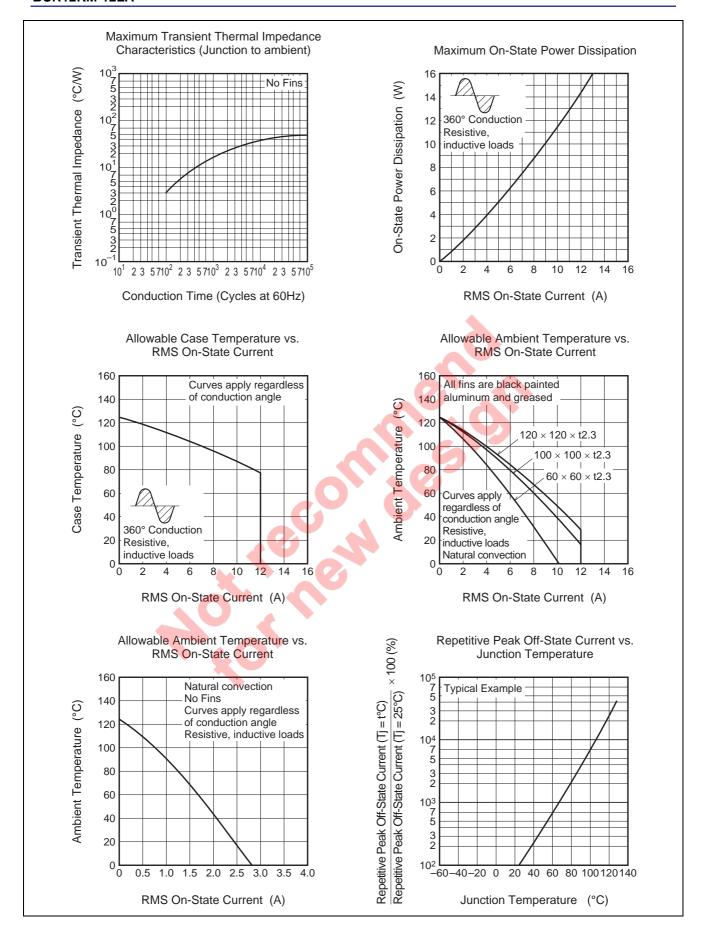
Notes: 2. Measurement using the gate trigger characteristics measurement circuit.

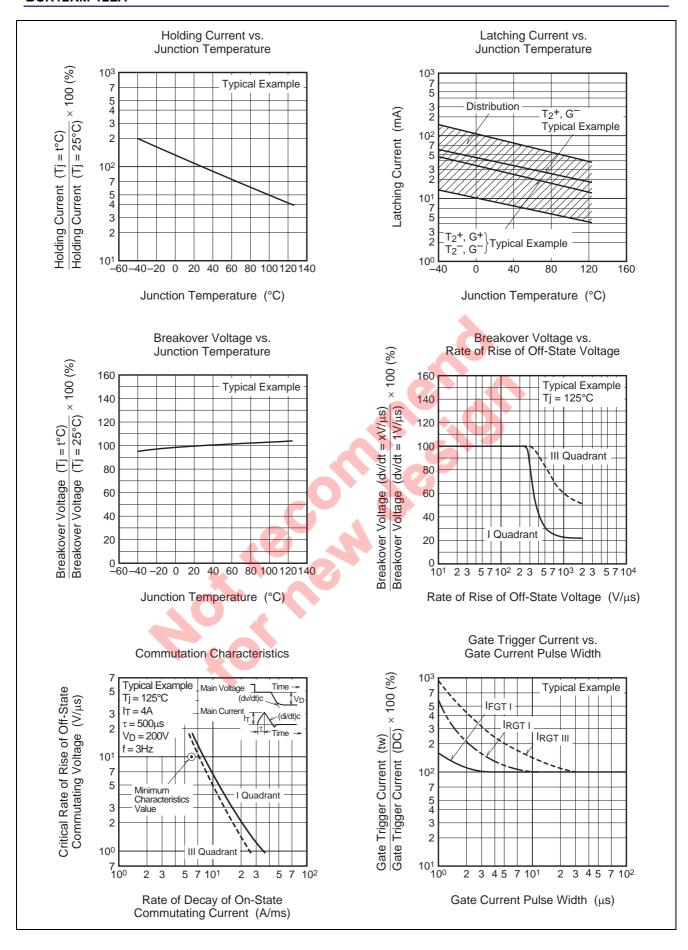
- 3. The contact thermal resistance R<sub>th (c-f)</sub> in case of greasing is 0.5°C/W.
- 4. Test conditions of the critical-rate of rise of off-state commutating voltage is shown in the table below.
- 5. High sensitivity ( $I_{GT} \le 20 \text{ mA}$ ) is also available. ( $I_{GT}$  item: 1)

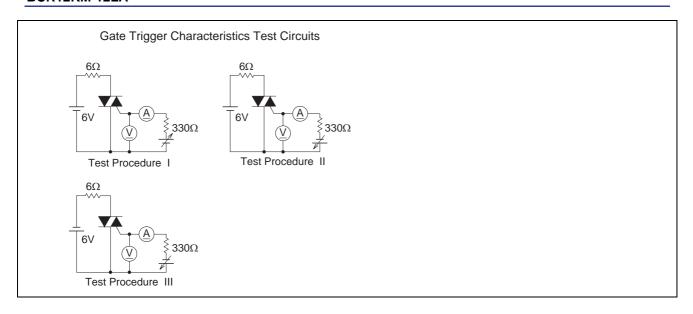
| Test conditions                                                                          | Commutating voltage and current waveforms (inductive load) |  |  |
|------------------------------------------------------------------------------------------|------------------------------------------------------------|--|--|
| 1. Junction temperature Tj = 125°C                                                       | Supply Voltage  → Time                                     |  |  |
| <ol> <li>Rate of decay of on-state commutating current<br/>(di/dt)c = -6 A/ms</li> </ol> | Main Current (di/dt)c                                      |  |  |
| 3. Peak off-state voltage $V_D = 400 \text{ V}$                                          | Main Voltage Time                                          |  |  |

#### **Performance Curves**



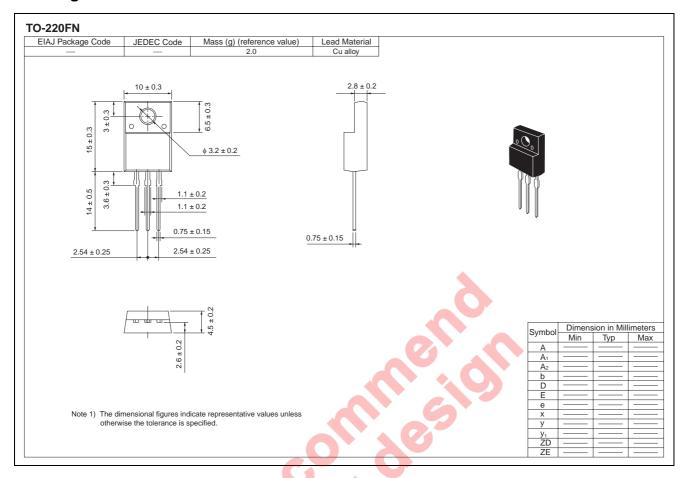








### **Package Dimensions**



#### **Order Code**

| Lead form     | Standard packing        | Quantity | Standard order code           | Standard order code example |
|---------------|-------------------------|----------|-------------------------------|-----------------------------|
| Straight type | Plastic Magazine (Tube) | 50       | Type name                     | BCR12KM-12LA                |
| Lead form     | Plastic Magazine (Tube) | 50       | Type name – Lead forming code | BCR12KM-12LA-A8             |

Note: Please confirm the specification about the shipping in detail.

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